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Crossover in the magnetic response of single-crystalline Ba$_{1-x}$K$_x$Fe$_2$As$_2$ and Lifshitz critical point evidenced by Hall effect measurements

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We report on the doping evolution of magnetic susceptibility $\chi(T)$ and Hall coefficient $R_H$ in high-quality Ba$_{1-x}$K$_x$Fe$_2$As$_2$ compounds. The pairing interaction $\chi(T)$ of optimally doped samples (0.34 $\leq x \leq$ 0.47) still follows a monotonic increase with increasing temperature, a big hump around 300 K emerges. As $x$ increases, a broad peak forms in underdoped samples (0.53 $\leq x \leq$ 1.0), which shifts toward 120 K for the end member KFe$_2$As$_2$. Above the peak temperature $T^*$ = 120 K, a Curie-Weiss-like behavior is observed in KFe$_2$As$_2$. The Hall coefficient $R_H$ of underdoped sample $x = 0.22$ shows a rapid increase above spin-density-wave transition temperature $T_{SDW}$. Below $T_{SDW}$, it increases slowly. $R_H$ of optimally doped and slightly underdoped samples (0.34 $\leq x \leq$ 0.65) shows relatively weak temperature dependence and a saturation tendency below 150 K. However, $R_H$ of K heavily overdoped samples (0.80 $\leq x \leq$ 1.0) increases rapidly below 150 K. Meanwhile, the Hall angle cot$\theta_H$ displays a concave temperature dependence in the entire doping range 0.22 $\leq x \leq$ 0.65, whereas it changes to a convex temperature dependence within the doping range 0.65 $\leq x \leq$ 1.0. The dramatic change coincides with the Lifshitz transition occurring around the critical doping $x = 0.80$, where angle photoemission spectroscopy measurements had confirmed that the electron pocket disappears with excess hole doping in the Ba$_{1-x}$K$_x$Fe$_2$As$_2$ system. It is suggested that the characteristic temperature $T^*$ of around 120 $\sim$ 150 K observed in susceptibility and the Hall coefficient, as well as previously reported resistivity data, may indicate an incoherence-coherence crossover in the Ba$_{1-x}$K$_x$Fe$_2$As$_2$ system.

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I. INTRODUCTION

Novel magnetism and multiband structure are two key aspects in the research of iron-based superconductors [1–6]. Parent compounds such as LaOFeAs and BaFe$_2$As$_2$ show a spin-density-wave (SDW) transition at $T_{SDW}$ 140 K [7,8], coupled with a phase transition from tetragonal to orthorhombic structures. The normal state of iron-based superconductors is a strongly correlated metal and the parent compound is a bad metal at the verge of the metal-insulator transition [9]. By alloying and isovalent ion doping or an application of pressure, the SDW order is suppressed, while a superconducting dome emerges with increasing doping levels in the phase diagram [1,2]. The primary pairing interaction was proposed to be mediated by antiferromagnetic (AFM) spin fluctuations. As a result, the superconducting state was expected to be the $s_\pm$ state, i.e., extended $s$-wave pairing with a sign reversal of the order parameter between different Fermi surface sheets [10]. Among the iron-based superconductors, the Ba$_{1-x}$K$_x$Fe$_2$As$_2$ system is quite unique. The optimally doped sample $x = 0.4$ displays a $T_c$ of 38 K. With increasing K doping level, $T_c$ steadily decreases to 3.8 K for the end member KFe$_2$As$_2$ [11]. It was found that the electronic structure of Ba$_{1-x}$K$_x$Fe$_2$As$_2$ compounds shows a dramatic change from optimally doped to overdoped samples [12,13]. Accompanied with the evolution of electronic structure, the pairing symmetry seems to change from $s_\pm$ wave in optimally doped samples to $d$ wave in KFe$_2$As$_2$ [14]. Recent angle-resolved photoemission spectroscopy (ARPES) found that the Fermi surface (FS) topology of the Ba$_{0.8}$K$_{0.2}$Fe$_2$As$_2$ single crystal is similar to that of KFe$_2$As$_2$, but differs from that of Ba$_{0.3}$K$_{0.7}$Fe$_2$As$_2$, which was interpreted within the framework of the Lifshitz transition occurring between $0.7 \leq x \leq 0.9$ [15]. Theoretical calculations also pointed out that the dissolution of electron cylinders occurs near $x \sim 0.9$ with Lifshitz transition in Ba$_{1-x}$K$_x$Fe$_2$As$_2$ superconductors [16]. The doping-dependent FS reconstruction is also evidenced by the change of thermoelectric power $S_{ab}$ for overdoped Ba$_{1-x}$K$_x$Fe$_2$As$_2$ single crystals, where the maximum at around 120 K in temperature dependence of $S_{ab}$ collapses into a plateau at $x \sim 0.8$–0.9 [17].

The transport property of the Ba$_{1-x}$K$_x$Fe$_2$As$_2$ system also shows different behavior, compared to electron-doped Ba(Fe$_{1-x}$Co$_x$)$_2$As$_2$ and isovalent-doped BaFe$_2$(As$_{1-x}$P$_x$)$_2$. A linear-$T$ dependence of in-plane resistivity $\rho_{ab}$ was universally observed in the optimally doped BaFe$_2$(As$_{1-x}$P$_x$)$_2$ [18], Ba(Fe$_{1-x}$Co$_x$)$_2$As$_2$ [19], and Ba(Fe$_{1-x}$Ni$_x$)$_2$As$_2$ [20] single crystals, while the Fermi liquid behavior $n \sim 2$ was observed in the overdoped regime by a fit of the power law $\rho_{ab} = \rho_0 + AT^n$. It is noted that the exponent $n \sim 1.5$ in optimally doped Ba(Fe$_{1-x}$Ni$_x$)$_2$As$_2$ samples was reported by a different group [21]. For Ba$_{1-x}$K$_x$Fe$_2$As$_2$ single crystals, however, it was found that $\rho_{ab}$ actually follows a $T^{1.5}$ dependence in the optimally doped regime. And the $T^2$ term contributes a lot in the entire doping range $0.22 \leq x \leq 1$ [22]. In an early report
on the transport properties of Ba$_{1-x}$K$_x$Fe$_2$As$_2$ single crystals within the low K doping regime (0 $\leq x \leq 0.4$), it was found that the power exponent $n$ evolves from 2 for the undoped samples to 1 at optimal doping $x = 0.37$ [23]. The discrepancy may result from different temperature windows for the fits of power law and quality of single crystals. Furthermore, all superconducting Ba$_{1-x}$K$_x$Fe$_2$As$_2$ samples from underdoped to overdoped regimes show a saturation tendency above 100 K [22].

In this study, we report the doping evolution of normal-state magnetic susceptibility, the Hall coefficient, and the Hall angle in Ba$_{1-x}$K$_x$Fe$_2$As$_2$ (0.13 $\leq x \leq 1$) single crystals. We find that magnetic susceptibility $\chi(T)$ monotonically increases with increasing temperature for the underdoped and optimally doped samples 0.13 $\leq x \leq 0.47$. A broad peak emerges as $x$ exceeds 0.53, which suggests different magnetic interactions in the overdoped regime. Intriguingly, we observed a dramatic change of Hall coefficient $R_H$ and Hall angle $\cot \theta_H$ as $x$ crosses the doping $x = 0.80$, where the Lifshitz transition occurs with the change of FS topology evidenced by ARPES measurement [15] and suggested by theoretical calculations [16].

II. EXPERIMENTAL DETAILS

High-quality Ba$_{1-x}$K$_x$Fe$_2$As$_2$ (0.13 $\leq x \leq 1$) single crystals were grown by using the self-flux method [22,24]. The crystals can be easily cleaved into thin plates along the $ab$ plane. Magnetic susceptibility $\chi(T)$ and Hall resistivity $\rho_{xy}$ were measured by using a physical property measurement system (PPMS, Quantum Design). For the measurements of magnetic susceptibility, the magnetic field $H$ was applied parallel to the $ab$ plane ($H \parallel ab$) and perpendicular to the $ab$ plane ($H \parallel c$). Nearly ten pieces of crystals with amounts of 20 $\sim$ 40 mg were piled along the $c$ axis for each measurement. In order to further clarify the intrinsic magnetic response of the samples, the magnetization as a function of applied field $H$ was measured at a series of fixed temperatures. The temperature dependence of magnetic susceptibility curves was verified by the susceptibility data extracted from field-dependent behavior. For the high-temperature susceptibility measurements, the crystals were glued on a heat stick (PPMS VSM oven) by using cement.

The Hall resistivity $\rho_{xy}$ was measured in magnetic field dependence at fixed temperatures. Because of the small Hall signal, misaligned contacts lead to a significant contribution to Hall voltage from the longitudinal resistivity $\rho_{xx}$. In order to avoid this problem, the Hall signal can be extracted from the slope of linear field dependence of Hall voltage by sweeping magnetic field. The Hall coefficient is then calculated as $R_H = \frac{V_H}{I_x d T}$, where $V_H$ is Hall voltage, $d$ is thickness of the thin plate-like crystals, $I_x$ is driven current, and $H$ is applied magnetic field. The thin flakes with a thickness of 10–30 $\mu$m were obtained by peeling off single crystals using adhesive tape. Five probe contacts were made by soldering the gold wires to the single crystals. The driven current of 1 mA and 19 Hz was used in the Hall effect measurements. Two pieces of crystals were measured for each K doping to check the reproducibility of the Hall data.

III. RESULTS AND DISCUSSION

It is important to clarify the intrinsic magnetic response of iron-based superconductors because they may contain ferromagnetic inclusions [1]. Figures 1(a) and 1(b) show the isothermal magnetization curves of KFe$_2$As$_2$ single crystal for (a) $H \parallel ab$ and (b) $H \parallel c$, measured at 45, 100, 150, 200, 250, and 300 K. (c) Temperature dependence of magnetic susceptibility $\chi(T)$ of KFe$_2$As$_2$ single crystal is measured by an application of magnetic field of 9 T, represented by solid lines. Solid squares correspond to the susceptibility data obtained from the linear fit of isothermal magnetization curves.

FIG. 1. (Color online) Isothermal magnetization curves of KFe$_2$As$_2$ single crystal for (a) $H \parallel ab$ and (b) $H \parallel c$, measured at 45, 100, 150, 200, 250, and 300 K. (c) Temperature dependence of magnetic susceptibility $\chi(T)$ of KFe$_2$As$_2$ single crystal is measured by an application of magnetic field of 9 T, represented by solid lines. Solid squares correspond to the susceptibility data obtained from the linear fit of isothermal magnetization curves.

FIGURES 2(a) and 2(b) show temperature dependence of magnetic susceptibility $\chi(T)$ of Ba$_{1-x}$K$_x$Fe$_2$As$_2$ (0.13 $\leq x \leq 1$) single crystals for $H \parallel ab$ and $H \parallel c$, respectively. Underdoped sample $x = 0.13$ displays a kink at $T_{SDW} \sim 110$ K, which matches the SDW transition temperature in the phase diagram [11,26]. Above $T_{SDW}$, a linear-$T$ susceptibility $\chi(T)$ is observed. For the optimally doped samples $x = 0.34$, 0.39, and 0.47, $\chi(T)$ still maintains monotonic increase with
Increasing temperature. But the susceptibility curves display a slightly down-bending behavior, not strictly following the linear relationship. With further increase of the K doping levels, $\chi(T)$ curves of overdoped samples ($0.53 \leq x \leq 0.65$) flatten out, compared to a gradual fall observed in underdoped and optimally doped samples. A big hump ranging from $T_c$ to room temperature is observed. This big hump further evolves into a broad peak centered at 120 K for KFe$_2$As$_2$. A Curie-Weiss tail is observed at the low-temperature regime above $T_c$ for K heavily doped samples ($0.80 \leq x \leq 1$). It is noted that the magnitude of $\chi(T)$ increases from underdoped to overdoped samples, showing a similar doping-dependent behavior to that observed in polycrystalline samples [27]. In Fig. 2(c) we show the temperature dependence of the anisotropy ratio $\chi_{ab}/\chi_c$ for all studied crystals. As can be seen, the anisotropy ratios $\chi_{ab}/\chi_c$ fluctuate between 1.2 and 1.6.

In Fig. 3 we show the susceptibility data measured up to 800 K for the samples $x = 0.47$, 0.53, and 1. In order to identify the possible sample degradation at high temperatures, each measurement has been done on both warming and cooling. The discrepancy between the susceptibility data and Curie-Weiss law above 500 K can be explained as the sample degrading above this temperature.
susceptibility with temperature. The theory can well explain the puzzle of large but fluctuating Fe moments [29].

In Figs. 2 and 3 we already demonstrated a crossover from the linear increase to the broad peak in $\chi(T)$ of Ba$_{1-x}$K$_x$Fe$_2$As$_2$ single crystals. We notice that Co doping leads to a decrease of magnetic susceptibility of Ba(Fe$_{1-x}$Co$_x$)$_2$As$_2$ with increasing Co doping levels [30]. In the Ba$_{1-x}$K$_x$Fe$_2$As$_2$ system, however, magnetic susceptibility is enhanced with increasing K doping levels. There are already several reports on the origin of linear-$T$ dependence of $\chi(T)$ in iron base superconductors [31–34]. It was suggested that strong AFM fluctuations with local SDW correlation give rise to the anomalous linear-$T$ dependence of $\chi(T)$ [31].

Soon it was argued that the linear in $T$ dependence of $\chi(T)$ is closely related to the anomalous magnetic interactions in iron base superconductors [31–34]. It was suggested that KFe$_2$As$_2$ is a strongly correlated material with local moments exist in KFe$_2$As$_2$ single crystal comes from its heavy fermion feature. The large Sommerfeld constant $\gamma_n$ of KFe$_2$As$_2$ single crystal is determined by the heavy fermion liquid, which favors the itinerant scenario for iron pnictides [32]. Skornyakov et al. [33,34] further demonstrated that linear-$T$ dependence of $\chi(T)$ in iron pnictides can be reproduced without invoking AFM fluctuations by employing the local density approximation plus the dynamical mean field method. Furthermore, contributions to the temperature dependence of the uniform susceptibility are strongly orbitally dependent. For high temperatures ($>1000$ K) susceptibility first saturates and then decreases with temperature [33,34]. Through $^{75}$As nuclear magnetic resonance (NMR) measurements on overdoped Ba$_{1-x}$K$_x$Fe$_2$As$_2$ ($x = 0.7$ and $1.0$) single crystals, it was found that the spin-lattice relaxation $1/T_1$ dramatically increases from the sample $x = 0.7$ to the $x = 1.0$, suggesting that another type of spin fluctuation develops at the doping close to $x = 1.0$ [35]. Hirano et al. [36] performed $^{75}$As NMR and nuclear quadrupole resonance (NQR) measurements on Ba$_{1-x}$K$_x$Fe$_2$As$_2$ ($0.27 \leq x \leq 1$) single crystals. In the normal state, $1/T_1$ has a strong temperature dependence, which indicates the existence of large AFM spin fluctuations for all the studied crystals. Hardy et al. suggested that KFe$_2$As$_2$ is a strongly correlated material with highly renormalized values of both the Sommerfeld coefficient and the Pauli susceptibility [25]. The magnetic susceptibility of KFe$_2$As$_2$ can be comparable to that of the heavy fermon CeRu$_2$S$_2$ which is FM state but close to AFM instability [25]. Therefore, the enhanced magnetism with increasing K content is closely related to the anomalous magnetic interactions in KFe$_2$As$_2$.

An explanation on the origin of the maximum in $\chi(T)$ of the KFe$_2$As$_2$ single crystal comes from its heavy fermion feature. The large Sommerfeld constant $\gamma_n = 94 \sim 107$ mJ/mol K$^2$ reported in high-quality KFe$_2$As$_2$ single crystals [25,37,38] implies a close relationship with heavy fermion compounds. Given that local moments exist in KFe$_2$As$_2$, the low-temperature maximum of $\chi(T)$ can be interpreted within the framework of two-fluid behavior suggested for the magnetic response of heavy electron materials [39,40]. The susceptibility in heavy electron materials is suggested to be the sum of three contributions: conduction electron spins $\chi_{cc}$, local moment spins $\chi_{ff}$, and the hybridization of conduction and localized electrons $\chi_{cf}$. At high temperatures $\chi_{cc}$ is given by the temperature-independent Pauli susceptibility of the conduction electrons, and $\chi_{ff}$ is given by the Curie-Weiss susceptibility of the local moments. The heavy electron Kondo liquid emerges below the characteristic temperature $T^*$ as a collective hybridization-induced instability of the spin liquid that describes the lattice of local moments coupled to background conduction electrons. Above $T^*$, $\chi_{ff}$ dominates. Below $T^*$, $\chi_{cf}$ becomes significant. $T^*$ is determined by the effective Ruderman-Kittel-Kasuya-Yosida (RKKY) interaction between the nearest-neighbor local moments [39,40]. It is therefore suggested that the maximum in $\chi(T)$ of KFe$_2$As$_2$ indicates the growth of hybridization of conduction and localized electrons with decreasing temperature.

Let us turn to the normal-state transport properties. Figure 4 illustrates an example of how the analysis of the Hall signal was processed for the sample $x = 0.92$. The raw data can be decomposed into three terms as $V = V_{\text{offset}} + V_H H + V_{HH} H^2$, where $V_{\text{offset}}$ corresponds to the contribution of longitudinal resistivity $\rho_{xx}$ between the Hall contact, and $V_H$ and $V_{HH}$ are Hall voltages from the linear-field-dependent term and $H^2$ contribution, respectively. After subtracting the $V_{\text{offset}}$ term in the raw data, Fig. 4(a) shows that the Hall voltage $V_H$ was measured as a function of applied field by sweeping the field from $-9$ to $9$ T at fixed temperatures. A nearly linear field dependence of $V_H$ is observed and the slopes $dV_H/dH$ retain positive values. The temperature dependence of Hall coefficient $R_H$ is shown in Fig. 4(b). The $V_{\text{offset}}$ term presents the temperature dependence of resistivity $\rho_{xx}$, as shown in Fig. 4(c). The good linear field dependence of raw data confirms the very weak contribution from the $H^2$ term, as illustrated in Fig. 4(d).

Figure 5 shows the temperature-dependent Hall coefficient $R_H$ of Ba$_{1-x}$K$_x$Fe$_2$As$_2$ ($0.22 \leq x \leq 1$) single crystals. As can be seen, for the underdoped sample $x = 0.22$, $R_H$ shows a rapid increases with decreasing temperature, and becomes a plateau at $T = 100$ K, where SDW transition occurs. For the sample $x = 0.34$, $R_H$ gradually increases with decreasing temperature but shows a saturation tendency below $T = 150$ K. With further increasing K doping levels, $R_H$ shows weak temperature dependence and a broad peak emerges at around $120–150$ K for the samples $x = 0.47, 0.53, 0.55$, and 0.65. All the samples $x = 0.34, 0.39, 0.47, 0.53, 0.55$, and 0.65 show a convex temperature dependence below $200$ K. As $x$ exceeds 0.80, the broad peak/big hump at around $120–150$ K disappears and $R_H$ shows a rapid increases below $T = 150$ K. A peak forms below $T = 50$ K before the samples enter into superconducting state. $R_H$ follows a concave temperature dependence within the temperature range $50 < T < 300$ K.

The doping dependence of Hall effect reflects the change of relevant electronic structure [41–43]. The knowledge about band structure and its doping evolution in Ba$_{1-x}$K$_x$Fe$_2$As$_2$ system comes from ARPES measurements. Early ARPES data revealed that undoped ($x = 0$) and optimally doped ($x = 0.4$ and 0.45) samples have double-walled electron pocket at the $M$ points of the BZ corner [44,45]. Zabolotnyy et al. [46,47] found that FS topology of the BZ corner is actually characteristic of a propeller-shaped structure, which consists of five small FS sheets: a central circular pocket surrounded by four blade-shaped pockets in Ba$_{1-x}$K$_x$Fe$_2$As$_2$ ($x = 0$ and 0.3) single crystals. The central circular pocket around $M$ points is electronlike, while FS sheets around the $\Gamma$ point and four blade pockets are holelike. The investigation on a wide doping range of Ba$_{1-x}$K$_x$Fe$_2$As$_2$ single crystals found that the gap size of the outer hole FS sheet around the BZ center shows an abrupt drop.
FIG. 4. (Color online) (a) Hall voltage $V_H$ of the $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ ($x = 0.92$) single crystal measured by sweeping the field from $-9 \, \text{T}$ to $9 \, \text{T}$ at selected temperatures. (b) Temperature dependence of Hall coefficient $R_H$ calculated from the linear term of the expression $V = V_{\text{offset}} + V_H H + V_{HH} H^2$. (c) The term $V_{\text{offset}}$ in the fit of raw data corresponds to the offset caused by longitudinal resistivity $\rho_{xx}$ between the Hall contacts. (d) The term $V_{HH}$ evaluates the contribution from the $H^2$ term, which is very small and can be neglected. Solid lines are guides to the eye.

FIG. 5. (Color online) Temperature dependence of Hall coefficient $R_H$ for $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ ($0.22 \leq x \leq 0.65$) (upper panel) and $0.80 \leq x \leq 1$ (bottom panel) single crystals. Arrows indicate the kink corresponding to the SDW transition and the broad peak observed in the samples $x = 0.53$, 0.55, and 0.65. Solid lines are guides to the eye.

with overdoping (for $x \geq 0.6$) while the inner and middle FS gaps roughly scale with $T_c$ [12]. In the $\text{KFe}_2\text{As}_2$ single crystal, the FS around the BZ center was found to be qualitatively similar to that of the $\text{Ba}_{0.6}\text{K}_{0.4}\text{Fe}_2\text{As}_2$ single crystal, but the electron pockets centered at the $M$ points are completely absent due to an excess of hole doping [13]. More detailed analysis of APRES data on the samples $x = 0.9$ suggested the Lifshitz transition occurred between $0.7 < x < 0.9$ [15], which is supported by the theoretical calculations [16]. Accordingly, the pairing symmetry was suggested to change from $s$ wave in optimally doped samples to $d$ wave in $\text{KFe}_2\text{As}_2$ [14]. But most possibly, the superconducting gap structure changes from the full gap state in the optimally doped samples into the nodal-line structure state for $\text{KFe}_2\text{As}_2$ [48,49].

It is noted that the broad peak/plateau in $R_H$ of $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ single crystals collapses in the overdoped samples ($0.80 \leq x \leq 1$), which coincides with the critical point where the electron pocket disappears and the Lifshitz transition occurs. The overall behavior of doping-dependent $R_H$ is therefore related to the change of FS topology. Evtyushinsky et al. [50] had calculated the temperature dependence of Hall coefficient $R_H$ of optimally doped $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ based the propeller-like FS topology observed by ARPES experiments. The agreement suggested that the temperature dependence of Hall coefficient $R_H$ has the basis that FS evolves to a propeller-like structure at the low-temperature regime. It should be pointed out that the same maximum of $R_H$ had been observed by Ohgushi et al. [51] in the Hall effect measurements.
on $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ ($0 \leq x \leq 0.55$) single crystals, which had been interpreted as an anomalous coherent state characterized by heavy quasiparticles in hole bands evolving below $T \sim 100$ K. The relatively weak temperature dependence observed in the optimally doped samples may suggest that incoherence-coherence crossover is less pronounced. Our results strongly suggest that the maximum of $R_H$ observed within the doping range $0.47 \leq x \leq 0.65$ as well as the temperature-dependent behavior observed in the samples $x = 0.22, 0.34,$ and $0.39$ are related to the contribution from the electron pocket at the $M$ points of the BZ. Without the contribution from the electron pocket, $R_H$ clearly drops at around $100 < T < 150$ K. In contrast to the electron-doped $\text{Ba}_(1-x)\text{Co}_x\text{Fe}_2\text{As}_2$, where the hole contribution to the transport can be neglected at low temperatures in most of the phase diagram [52], electron conductivity plays a significant role in the charge transport of $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ below the doping $x = 0.80$. The remarkable doping and temperature dependencies of the Hall coefficient $R_H$ in the $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ system suggest a dominant interband interaction between carriers having electron and hole character [53,54].

We further analyze the Hall angle $\cot \theta_H = \rho_{xx}/\rho_{xy}$ of $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ ($0.22 \leq x \leq 1$) single crystals. In our analysis, both longitudinal resistivity $\rho_{xx}$ and Hall resistivity $\rho_{xy}$ were normalized by their room temperature values. Therefore we have

$$\cot \theta_H = \frac{\rho_{xx}}{\rho_{xy}} = \frac{\rho_{xx}}{R_H H} \propto \frac{\rho_{xx}(300 \text{ K})}{R_H/R_H(300 \text{ K})}. \quad (1)$$

The detailed analysis of doping dependence of $\rho_{xx}$ can be found in Ref. [22]. The temperature dependence of Hall angle $\cot \theta_H$ is shown in Fig. 6. Interestingly, the Hall angle data can be clearly divided into two groups. Hall angle $\cot \theta_H$ displays a concave temperature dependence within the doping range $0.22 \leq x \leq 0.55$, whereas it changes to a convex temperature dependence within the doping range $0.65 \leq x \leq 1$. This feature again supports that the Lifshitz transition occurs at the critical doping $x = 0.65 \sim 0.80$.

In an early work, the power-law temperature dependent Hall angle, i.e., $\cot \theta_H = A + BT^\alpha$, was observed above a characteristic temperature $T^*$ in the entire phase diagram of the $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ system [55]. Figure 7 shows our Hall angle data in a double-logarithmic plot. As can be seen, there is a clear kink at around $T^* = 140$ K for the optimally doped samples $x = 0.34, 0.39, 0.47, 0.53,$ and $0.55$ (a) and inflection point that $\cot \theta_H$ has downward curvature above it and upward curvature below it for the samples $x = 0.80, 0.82, 0.90, 0.92,$ and $1$ (b). Solid lines are guides to the eye.

FIG. 6. (Color online) Temperature dependence of Hall angle $\cot \theta_H$ for $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ ($0.22 \leq x \leq 1$) single crystals. A concave temperature dependence is observed within the doping range $0.22 \leq x \leq 0.55$, whereas it dramatically changes to a convex temperature dependence within the doping range $0.65 \leq x \leq 1$. Solid lines are guides to the eye.

FIG. 7. (Color online) Temperature dependence of Hall angle $\cot \theta_H$ for $\text{Ba}_{1-x}\text{K}_x\text{Fe}_2\text{As}_2$ ($0.22 \leq x \leq 0.65$) (upper panel) and ($0.80 \leq x \leq 1$) (bottom panel) single crystals in double logarithmic plots. The arrows indicates the kink where slopes change for the samples $x = 0.34, 0.39, 0.47, 0.53,$ and $0.55$ (a) and inflection point that $\cot \theta_H$ has downward curvature above it and upward curvature below it for the samples $x = 0.80, 0.82, 0.90, 0.92,$ and $1$ (b). Solid lines are guides to the eye.
the analysis of the Hall angle also supports the existence of characteristic temperature $T^*$, which is suggested to be related to the incoherence-coherence crossover. Assuming two types of charge carriers in the Ba$_{1-x}$K$_x$Fe$_2$As$_2$ system \cite{56}, above $T^*$, highly incoherent charge carriers dominate, whereas coherent ones become significant below it. Here the coherence process is related to the hybridization of conduction charge carriers and local spin moments, which gives rise to a large effective mass of conduction charge carriers. The overall behavior of magnetic susceptibility, Hall coefficient, and resistivity provides evidence of incoherence-coherence crossover at $T^*$ in the Ba$_{1-x}$K$_x$Fe$_2$As$_2$ system. The coherent charge dynamics in BaFe$_2$As$_2$(As$_{1-x}$P$_x$)$_2$ and Ba(Fe$_{1-x}$Co$_x$)$_2$As$_2$ systems is more pronounced than the Ba$_{1-x}$K$_x$Fe$_2$As$_2$ system in the normal state \cite{56}. It could be the reason why the coherence-incoherence crossover is not observed in resistivity and magnetic susceptibility of BaFe$_2$As$_2$(As$_{1-x}$P$_x$)$_2$ and Ba(Fe$_{1-x}$Co$_x$)$_2$As$_2$ systems.

IV. CONCLUSIONS

In summary, we have performed magnetic susceptibility $\chi(T)$ and Hall coefficient $R_H$ measurements on a series of Ba$_{1-x}$K$_x$Fe$_2$As$_2$ single crystals. A crossover from the SDW ordered state to KFe$_2$As$_2$-type magnetic interactions occurs with increasing K content. It is found that $\chi(T)$ monotonically increases with increasing temperature for the underdoped and optimally doped samples $0.13 \leq x \leq 0.47$. For the overdoped samples $0.53 \leq x \leq 1$, a big hump was observed at around 150 K, and it eventually evolves into a broad peak in KFe$_2$As$_2$ at 120 K. The magnitude of magnetic susceptibility keeps increasing with increasing K content. The Hall coefficient $R_H$ and Hall angle cot$\theta_H$ display a dramatic change as $x$ exceeds 0.80, which coincides with the critical doping point where the electron pocket disappears with excess hole doping. Our results strongly suggest that the change of doping dependence of Hall coefficient $R_H$ and Hall angle cot$\theta_H$ is related to the change of FS topology, i.e., the Lifshitz transition. The characteristic temperature $T^*$ is identified in magnetic susceptibility, Hall coefficient, and resistivity data, which strongly suggests the incoherence-coherence crossover occurred in the Ba$_{1-x}$K$_x$Fe$_2$As$_2$ system.

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